# **PNZ150** (PN150)

# Silicon planar type

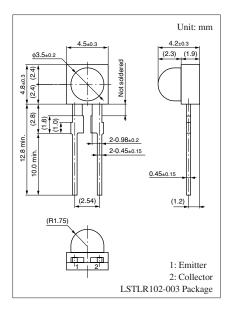
### For optical control systems

#### ■ Features

- · High sensitivity
- Wide spectral sensitivity characteristics, suited for detecting GaAs LEDs
- · Low dark current
- Side-view plastic mold type package

## ■ Absolute Maximum Ratings $T_a = 25$ °C

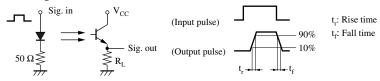
Parameter	Symbol	Rating	Unit	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	20	V	
Collector current	$I_C$	20	mA	
Collector power dissipation	P <sub>C</sub>	100	mW	
Operating ambient temperature	$T_{opr}$	-25 to +85	°C	
Storage temperature	$T_{stg}$	-30 to +100	°C	



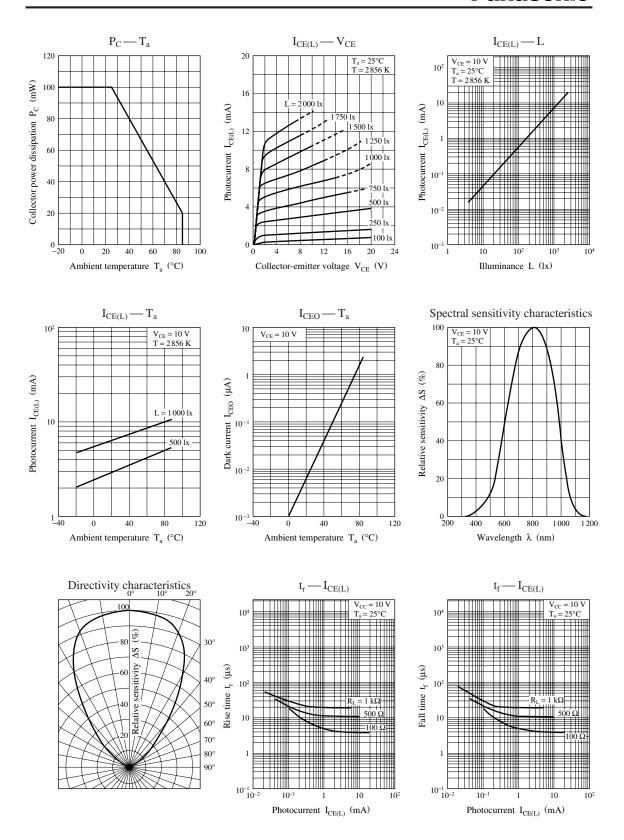
### ■ Electrical-Optical Characteristics $T_a = 25$ °C $\pm 3$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Photocurrent *1	I <sub>CE(L)</sub>	$V_{CE} = 10 \text{ V}, L = 500 \text{ lx}$	1.0	3.0		mA
Dark current	$I_{CEO}$	$V_{CE} = 10 \text{ V}$		0.01	1.00	μΑ
Peak emission wavelength	$\lambda_{\mathrm{p}}$	$V_{CE} = 10 \text{ V}$		800		nm
Half-power angle	θ	The angle from which photocurrent		35		0
		becomes 50%				
Rise time *2	t <sub>r</sub>	$V_{CC} = 10 \text{ V}, I_{CE(L)} = 5 \text{ mA}, R_L = 100 \Omega$		4		μs
Fall time *2	t <sub>f</sub>			4		μs
Collector-emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_{CE(L)} = 1 \text{ mA}, L = 1000 \text{ lx}$		0.2	0.5	V

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
  - 2. Spectral sensitivity characteristics: Sensitivity for wave length over 400 nm maximum sensitivity ratio is 100%.
  - 3. This device is designed be dis regarded radiation.
  - 4. \*1: Source: Tungsten (color temperature 2856 K)
    - \*2: Switching time measurement circuit



Note) The part number in the parenthesis shows conventional part number.



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